LSF0204

4-bit bidirectional multi-voltage level translator; open-drain; push-pull

Rev. 3.1 — 25 July 2024

Product data sheet

1. General description

The LSF0204 is an 4 channel bidirectional multi-voltage level translator for open-drain and push-pull applications. It supports up to 100 MHz up translation and ≥ 100 MHz down translation at ≤ 30 pF capacitive load. There is no need for a direction pin which minimizes system effort. The LSF0204 supports 5 V tolerant I/O pins for compatibility with TTL levels in a variety of applications. The ability to set up different voltage translation levels on each channel makes the device very flexible and suitable for a lot of different applications.

2. Features and benefits

- · Bidirectional voltage translation with no direction pin
- Up translation
 - \leq 100 MHz; C_L = 15 pF, 30 pF
 - \leq 50 MHz; $C_L = 50 pF$
- Down translation
 - ≥ 100 MHz; C_L = 15 pF, 30 pF
 - ≥ 50 MHz; C_L = 50 pF
- · Hot insertion
- Bidirectional voltage level translation between:
 - 0.8 V and 1.8 V, 2.5 V, 3.3 V and 5.0 V
 - 1.2 V and 1.8 V, 2.5 V, 3.3 V and 5.0 V
 - 1.8 V and 2.5 V, 3.3 V and 5.0 V
 - 2.5 V and 3.3 V and 5.0 V
 - 3.3 V and 5.0 V
- Low standby current
- 5 V tolerant I/O pins to support TTL
- Low R_{ON} provides less signal distortion
- Latch-up performance exceeds 100 mA per JESD78 class II level A
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Specified from -40 °C to +125 °C

3. Applications

- GPIO, MDIO, PMBus, SMBus, SDIO, UART, I²C, and other interfaces in Telecom infrastructure
- Industrial
- Personal computing



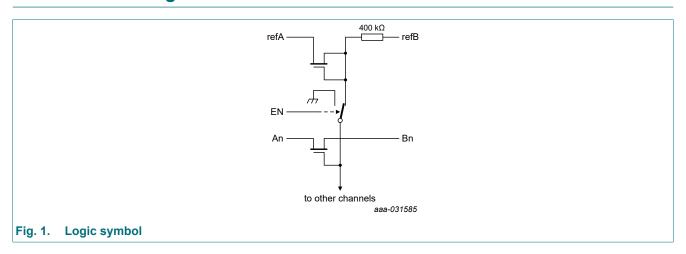
4-bit bidirectional multi-voltage level translator; open-drain; push-pull

4. Ordering information

Table 1. Ordering information

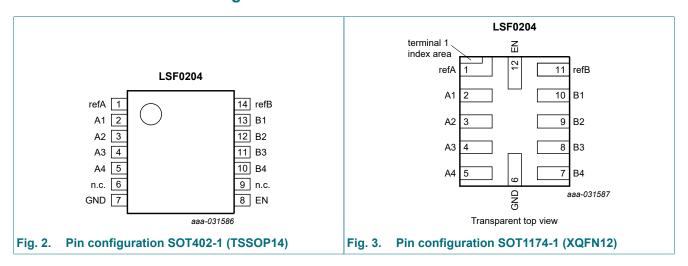
Type number	Package	ckage							
	Temperature range	Name	Description	Version					
LSF0204PW	-40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package; 14 leads; body width 4.4 mm	SOT402-1					
LSF0204GU12	-40 °C to +125 °C	XQFN12	plastic, extremely thin quad flat package; no leads; 12 terminals; body 1.70 × 2.0 × 0.50 mm	SOT1174-1					

5. Functional diagram



6. Pinning information

6.1. Pinning



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6.2. Pin description

Table 2. Pin description

Symbol	Pin		Description
	TSSOP14	XQFN12	
refA	1	1	reference voltage A (EN input circuit is referenced to refA)
A1, A2, A3, A4	2, 3, 4, 5	2, 3, 4, 5	data input/output A
n.c.	6, 9	-	not connected
GND	7	6	ground (0 V)
EN	8	12	enable input (active HIGH)
B1, B2, B3, B4	13, 12, 11, 10	10, 9, 8, 7	data input/output B
refB	14	11	reference voltage B

7. Functional description

Table 3. Function table

H = HIGH voltage level; L = LOW voltage level; Z = high-impedance OFF-state.

Input	input/output
EN[1]	An, Bn channel
Н	An = Bn
L	Z

[1] EN input circuit is referenced to refA

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
VI	input voltage	pins refA, refB, An, Bn and EN [1]	-0.5	+7.0	V
I _{I/O}	input/ouput current	pins refA, refB, An and Bn; continuous channel current	-	+128	mA
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	TSSOP14 package [2]	-	500	mW
		XQFN12 package	-	250	mW

- [1] The minimum input voltage rating may be exceeded if the input current rating is observed.
- [2] For SOT402-1 (TSSOP14) package: Ptot derates linearly with 7.3 mW/K above 81 °C.

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9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
VI	input voltage	pins refA, refB, An, Bn and EN	0.0	5.0	V
I _{I/O}	input/ouput current	pins refA, refB, An and Bn; continuous channel current	-	+64	mA
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	EN input	-	10	ns/V

10. Static characteristics

Table 6. Static characteristics

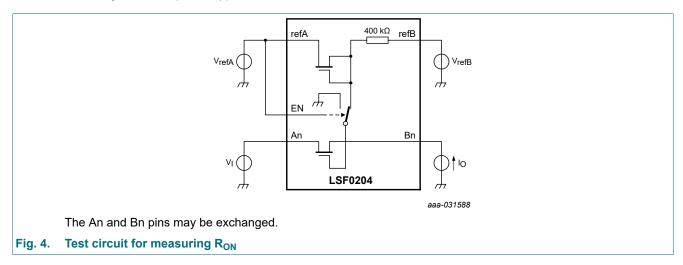
At recommended operating conditions voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	eter Conditions	T _{amb} =	-40 °C to	+125 °C	Unit
			Min	Typ [1]	Max	1
V _{IK}	input clamping voltage	$V_{I(EN)} = 0 \text{ V}; I_I = -18 \text{ mA}$	-1.2	-	-	V
I _{IH}	HIGH-level input current	$V_{I} = 5 \text{ V}; V_{I(EN)} = 0 \text{ V}$	-	-	5	μΑ
I _I	input current	EN input; V_{refA} = 4.5 V; V_{refB} = 5.5 V; $V_{I(EN)}$ = 0 V to V_{refA} ; I_O = 0 A	-	-	±1	μΑ
V _{IH}	HIGH-level EN input					
	input voltage	V _{refA} = 1.5 V to 4.5 V	0.7V _{refA}	-	-	V
		V _{refA} = 1.0 V to 1.5 V	0.8V _{refA}	-	-	V
V _{IL}	LOW-level	EN input				
	input voltage	V _{refA} = 1.5 V to 4.5 V	-	-	0.3V _{refA}	V
		V _{refA} = 1.0 V to 1.5 V	-	-	0.3V _{refA}	V
I _{refB-A}	leakage current refB to refA	$V_{refA} = V_{I(EN)} = 1.8 \text{ V}; V_{refB} = 3.3 \text{ V}; I_{O} = 0 \text{ A}; V_{I} = 3.3 \text{ V or GND}$	-	-	3.5	μA
I _{GND}	ground current	$V_{refA} = V_{I(EN)} = 1.8 \text{ V}; V_{refB} = 3.3 \text{ V}; I_{O} = 0 \text{ A}; V_{I} = 3.3 \text{ V or GND}$	-	0.2	-	μΑ
l _{OFF}	power-off leakage current	$V_{refA} = V_{refB} = V_{I(EN)} = 0 \text{ V}; I_O = 0 \text{ A}; V_I = 5 \text{ V or GND}$	-	-	±1	μA
C _I	input capacitance	pins refA, refB and EN; V _I = 3 V or 0 V	-	7	-	pF
C _{io(off)}	OFF-state input/output capacitance	pins An, Bn; $V_O = 0 \text{ V or } 3 \text{ V}$; $V_{I(EN)} = 0 \text{ V}$	-	3	6	pF
C _{io(on)}	ON-state input/output capacitance	pins An, Bn; $V_O = 0 \text{ V or } 3 \text{ V}$; $V_{I(EN)} = 3.0 \text{ V}$	-	8	13	pF

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Symbol	Parameter	Conditions		T _{amb} = -40 °C to +125 °C		
			Min	Typ [1]	Max	
R _{ON}	ON resistance	see <u>Fig. 4</u> [2]				
		V _I = 0 V; I _O = 64 mA;				
		$V_{refA} = V_{I(EN)} = 3.3 \text{ V}; V_{refB} = 5 \text{ V}$	-	3	-	Ω
		V _{refA} = V _{I(EN)} = 1.8 V; V _{refB} = 5 V	-	4	-	Ω
		$V_I = 0 \text{ V}; I_O = 32 \text{ mA};$				
		$V_{refA} = V_{I(EN)} = 1.0 \text{ V}; V_{refB} = 5 \text{ V}$	-	7	-	Ω
		$V_{refA} = V_{I(EN)} = 1.8 \text{ V}; V_{refB} = 5 \text{ V}$	-	4	-	Ω
		$V_{refA} = V_{I(EN)} = 2.5 \text{ V}; V_{refB} = 5 \text{ V}$	-	3.5	-	Ω
		V_{I} = 1.8 V; I_{O} = 15 mA; V_{refA} = $V_{I(EN)}$ = 3.3 V; V_{refB} = 5 V	-	5	-	Ω
		V_{I} = 1 V; I_{O} = 10 mA; V_{refA} = $V_{I(EN)}$ = 1.8 V; V_{refB} = 3.3 V	-	8	-	Ω
		$V_{I} = 0 \text{ V}; I_{O} = 10 \text{ mA}; V_{refA} = V_{I(EN)} = 1 \text{ V}; V_{refB} = 3.3 \text{ V}$	-	6	-	Ω
		$V_{I} = 0 \text{ V}; I_{O} = 10 \text{ mA}; V_{refA} = V_{I(EN)} = 1 \text{ V}; V_{refB} = 1.8 \text{ V}$	-	6	-	Ω

- 1] All typical values are measured at $T_{amb} = 25 \, ^{\circ}\text{C}$.
- [2] Measured by the voltage drop between the An and Bn pins at the indicated current through the switch. ON resistance is determined by the lowest voltage of the two (An or Bn) pins.



11. Dynamic characteristics

Table 7. Dynamic characteristics

GND = 0 V; for waveforms see $\underline{\text{Fig. 5}}$ and $\underline{\text{Fig. 6}}$; for test circuit see $\underline{\text{Fig. 7}}$

Symbol	Parameter	Conditions	T _{amb} = -40 °C to +125 °C		Unit	
			Min	Typ[1]	Max	
Translati	ng down (3.3 V to 1.8 V)		,			
t _{PLH}	LOW to HIGH	An to Bn or Bn to An				
	propagation delay	$V_{refA} = V_{I(EN)} = 1.8 \text{ V}; V_{refB} = 3.3 \text{ V}; V_{I} = 3.3 \text{ V}; V_{M} = 1.15 \text{ V}$				
		C _L = 15 pF	-	0.3	5.19	ns
		C _L = 30 pF	-	0.5	5.29	ns
		C _L = 50 pF	-	0.7	5.49	ns

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Symbol	Parameter	meter Conditions		T _{amb} = -40 °C to +125 °C			
			Min	Typ[1]	Max		
PHL	HIGH to LOW	An to Bn or Bn to An					
	propagation delay	$V_{refA} = V_{I(EN)} = 1.8 \text{ V}; V_{refB} = 3.3 \text{ V}; V_{I} = 3.3 \text{ V}; V_{M} = 1.15 \text{ V}$					
		C _L = 15 pF	-	0.5	4.5	ns	
		C _L = 30 pF	-	0.7	4.7	ns	
		C _L = 50 pF	-	0.9	4.9	ns	
PLZ	LOW to OFF-state	EN to An or Bn					
	propagation delay	$V_{refA} = V_{I(EN)} = 1.8 \text{ V}; V_{refB} = 3.3 \text{ V}; V_{M} = 1.15 \text{ V}$					
		C _L = 15 pF	-	11	15	ns	
		C _L = 30 pF	-	12	16.5	ns	
		C _L = 50 pF	-	13	18	ns	
PZL	OFF-state to LOW	EN to An or Bn					
	propagation delay	$V_{refA} = V_{I(EN)} = 1.8 \text{ V}; V_{refB} = 3.3 \text{ V}; V_{M} = 1.15 \text{ V}$					
		C _L = 15 pF	-	23	37	ns	
		C _L = 30 pF	-	30	40	ns	
		C _L = 50 pF	-	33	45	ns	
f _{max}	maximum frequency	V _{refA} = V _{I(EN)} = 1.8 V; V _{refB} = 3.3 V; V _I = 3.3 V; V _M = 1.15 V					
		C _L = 15 pF	-	120	-	MHz	
		C _L = 30 pF	-	120	-	MHz	
		C _L = 50 pF	-	100	-	MHz	
ranslati	ng down (3.3 V to 1.2 V						
PLH	LOW to HIGH	An to Bn or Bn to An					
	propagation delay	$V_{refA} = V_{I(EN)} = 1.2 \text{ V}; V_{refB} = 3.3 \text{ V}; V_{I} = 3.3 \text{ V}; V_{M} = 0.85 \text{ V}$					
		C _L = 15 pF	-	0.3	3.8	ns	
		C _L = 30 pF	-	0.5	3.9	ns	
		C _L = 50 pF	-	0.8	4.1	ns	
PHL	HIGH to LOW	An to Bn or Bn to An					
	propagation delay	$V_{refA} = V_{I(EN)} = 1.2 \text{ V}; V_{refB} = 3.3 \text{ V}; V_{I} = 3.3 \text{ V}; V_{M} = 0.85 \text{ V}$					
		C _L = 15 pF	-	0.6	4.3	ns	
		C _L = 30 pF	-	0.7	4.5	ns	
		C _L = 50 pF	-	0.9	4.7	ns	
max	maximum frequency	$V_{refA} = V_{I(EN)} = 1.2 \text{ V}; V_{refB} = 3.3 \text{ V}; V_{I} = 3.3 \text{ V}; V_{M} = 0.85 \text{ V}$					
		C _L = 15 pF	-	120	-	MHz	
		C _L = 30 pF	-	120	-	MHz	
		$C_L = 50 pF$	-	100	-	MHz	

4-bit bidirectional multi-voltage level translator; open-drain; push-pull

Symbol	Parameter	Conditions	T _{amb}	= -40 °C to +1	25 °C	Unit
			Min	Typ[1]	Max	
Γranslati	ng up (1.8 V to 3.3 V)					
PLH	LOW to HIGH	An to Bn or Bn to An				
	propagation delay	$V_{refA} = V_{I(EN)} = 1.8 \text{ V}; V_{refB} = 3.3 \text{ V}; V_{I} = 1.8 \text{ V}; V_{M} = 0.9 \text{ V}$				
		C _L = 15 pF	-	0.2	5.1	ns
		C _L = 30 pF	-	0.4	5.3	ns
		C _L = 50 pF	-	0.6	5.7	ns
PHL	HIGH to LOW	An to Bn or Bn to An				
	propagation delay	$V_{refA} = V_{I(EN)} = 1.8 \text{ V}; V_{refB} = 3.3 \text{ V}; V_{I} = 1.8 \text{ V}; V_{M} = 0.9 \text{ V}$				
		C _L = 15 pF	-	0.7	5.3	ns
		C _L = 30 pF	-	1	6.4	ns
		C _L = 50 pF	-	1.3	6.7	ns
PLZ	LOW to OFF-state	EN to An or Bn				
	propagation delay	$V_{refA} = V_{I(EN)} = 1.8 \text{ V}; V_{refB} = 3.3 \text{ V}; V_{M} = 0.9 \text{ V}$				
		C _L = 15 pF	-	11	15	ns
		C _L = 30 pF	-	12	16.5	ns
		C _L = 50 pF	-	13	18	ns
PZL	OFF-state to LOW propagation delay	EN to An or Bn				
		$V_{refA} = V_{I(EN)} = 1.8 \text{ V}; V_{refB} = 3.3 \text{ V}; V_{M} = 0.9 \text{ V}$				
		C _L = 15 pF	-	23	37	ns
		C _L = 30 pF	-	30	40	ns
		C _L = 50 pF	-	33	45	ns
max	maximum frequency	$V_{refA} = V_{I(EN)} = 1.8 \text{ V}; V_{refB} = 3.3 \text{ V}; V_{I} = 1.8 \text{ V}; V_{M} = 0.9 \text{ V}; R_{L} = 100 \Omega$				
		C _L = 15 pF	-	100	-	MHz
		C _L = 30 pF	-	100	-	MHz
		C _L = 50 pF	-	80	-	MHz
Translati	ng up (1.2 V to 1.8 V)					·
PLH	LOW to HIGH	An to Bn or Bn to An				
	propagation delay	$V_{refA} = V_{I(EN)} = 1.2 \text{ V}; V_{refB} = 1.8 \text{ V};$ $V_{I} = 1.2 \text{ V}; V_{M} = 0.6 \text{ V}$				
		C _L = 15 pF	-	0.2	6.85	ns
		C _L = 30 pF	-	0.4	7.05	ns
		C _L = 50 pF	-	0.65	7.25	ns
PHL	HIGH to LOW	An to Bn or Bn to An				
	propagation delay	$V_{refA} = V_{I(EN)} = 1.2 \text{ V}; V_{refB} = 1.8 \text{ V};$ $V_{I} = 1.2 \text{ V}; V_{M} = 0.6 \text{ V}$				
		C _L = 15 pF	-	1	5.4	ns
		C _L = 30 pF	-	1.3	6.5	ns
		C _L = 50 pF	-	1.6	7.03	ns

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Symbol	Parameter	Conditions	T _{amb} = -40 °C to +125 °C		Unit	
			Min	Typ[1]	Max	
f _{max}	maximum frequency	$V_{refA} = V_{I(EN)} = 1.2 \text{ V}; V_{refB} = 1.8 \text{ V}; V_{I} = 1.2 \text{ V}; V_{M} = 0.6 \text{ V}; R_{L} = 100 \Omega$				
		C _L = 15 pF	-	100	-	MHz
		C _L = 30 pF	-	100	-	MHz
		C _L = 50 pF	-	80	-	MHz

[1] All typical values are measured at T_{amb} = 25 °C.

11.1. Waveforms and test circuit

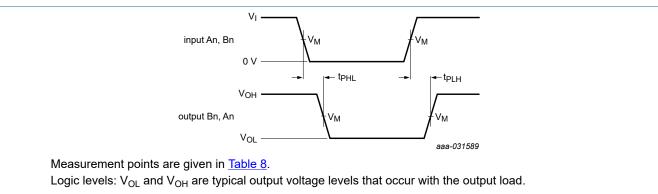
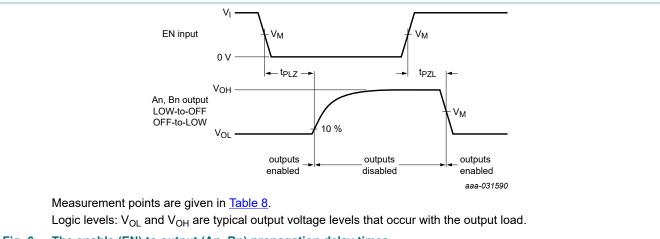
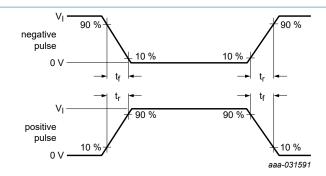


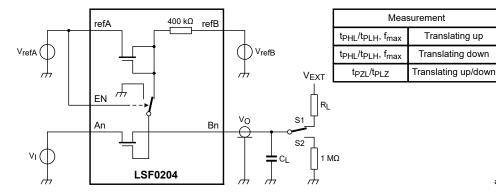
Fig. 5. The data input (An, Bn) to output (Bn, An) propagation delay times



4-bit bidirectional multi-voltage level translator; open-drain; push-pull



a. V_I source waveform



aaa-031592

switch

S1

S2 S1

Translating up

Translating down

b. Test circuit

Test data is given in Table 8; The An and Bn pins may be exchanged.

All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz; Z_O = 50 Ω . Definitions test circuit:

C_L = Load capacitance including jig and probe capacitance;

R_L = Load resistance;

S1/S2 = Test selection switch.

Fig. 7. Test circuit for measuring switching times

Table 8. Test data

Input	Load			V _{EXT}		
t _r , t _f	CL	R _L				
		t _{PLH} , t _{PHL} , t _{PLZ} , t _{PZL}	f _{max}	t _{PLH} , t _{PHL} , f _{max}	t _{PLZ} , t _{PZL} [1]	
≤ 2 ns	15 pF, 30 pF, 50 pF	500 Ω	100 Ω	V_{refB}	V _{refA} , V _{refB}	

[1] For measuring t_{PLZ} , t_{PZL} (translating up) $V_{EXT} = V_{refB}$. For measuring t_{PLZ} , t_{PZL} (translating down) $V_{EXT} = V_{refA}$.

4-bit bidirectional multi-voltage level translator; open-drain; push-pull

12. Package outline

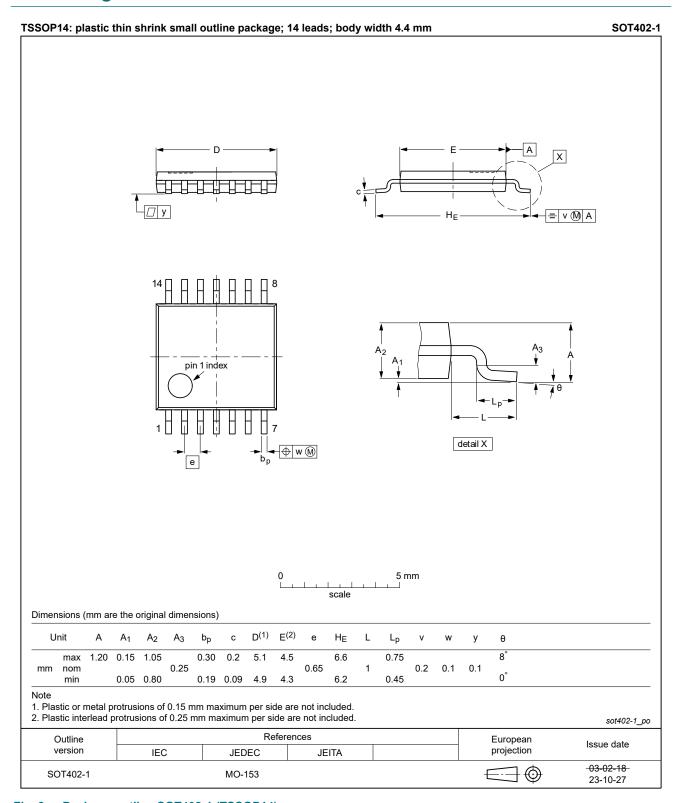


Fig. 8. Package outline SOT402-1 (TSSOP14)

4-bit bidirectional multi-voltage level translator; open-drain; push-pull

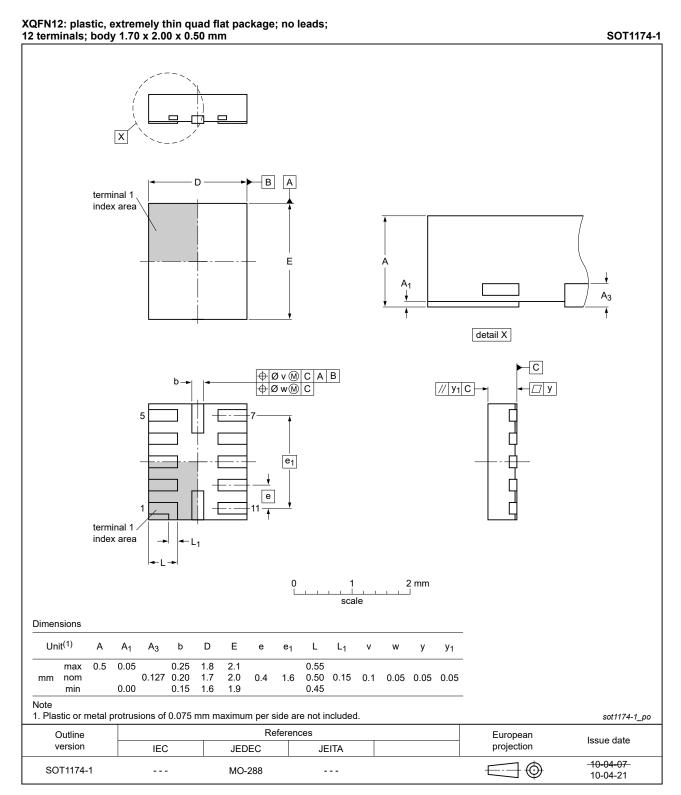


Fig. 9. Package outline SOT1174-1 (XQFN12)

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13. Abbreviations

Table 9. Abbreviations

Acronym	Description		
ANSI	American National Standards Institute		
CDM	Charged Device Model		
ESD	ElectroStatic Discharge		
ESDA	ElectroStatic Discharge Association		
НВМ	Human Body Model		
JEDEC	Joint Electron Device Engineering Council		
PRR	Pulse Rate Repetition		
TTL	Transistor-Transistor Logic		

14. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
LSF0204 v.3.1	20240725	Product data sheet	-	LSF0204 v.3		
LSF0204 v.3	20231128	Product data sheet	-	LSF0204 v.2		
Modifications:		 <u>Section 2</u>: up- and down-translation typo corrected. <u>Fig. 8</u>: SOT402-1 package outline drawing changed. 				
LSF0204 v.2	20201028	Product data sheet	-	LSF0204 v.1		
Modifications:		 Section 2 updated. Table 7: f_{max} values corrected. 				
LSF0204 v.1	20200518	Product data sheet	-	-		

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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4-bit bidirectional multi-voltage level translator; open-drain; push-pull

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